

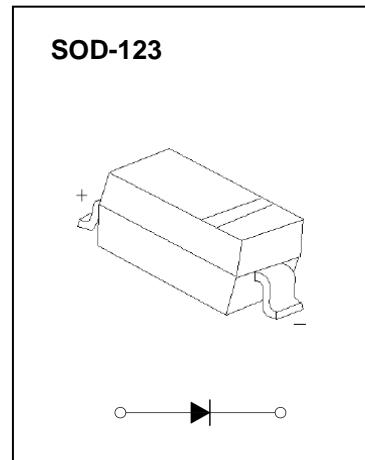


JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

SOD-123 Plastic-Encapsulate Diodes

RB160M-60 Schottky Barrier Diode**FEATURES**

- Small Power Mold Type
- Low I_R
- High Reliability

MARKING: 76**Maximum Ratings @Ta=25°C**

Parameter	Symbol	Limit	Unit
DC reverse voltage	V_R	60	V
Mean rectifying current	I_0	1	A
Peak forward surge current	I_{FSM}	30	A
Power dissipation	D_8	350	mW
Thermal Resistance Junction to Ambient	$\theta_F > 5$	286	°C/W
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55~+150	°C

Electrical characteristics @Ta=25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_F			0.58	V	$I_F=1A$
Reverse current	I_R			30	μA	$V_R=60V$